Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	4	"2002011612"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/09/26 20:44
S2	0	2002011612A1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/02/28 18:14
S3		"011612 A1"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/02/28 18:14
S4	0	"US2002011612"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/02/28 18:15 ·
S5	0	"20021118255"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/02/28 18:16
S6	2	"2002118255"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/02/28 18:17
<b>S7</b>		"2002261097"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2007/02/28 18:17
S8	2873	(((Nishimuta near (Takefumi K)) (Miyagi near (Hiroshi H))) (Ohmi near (Tadahiro T)) (Sugawa near (Shigetoshi S)) (Teramoto near (Akinobu A))).in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/02/28 18:23

S9	375896	"257".clas.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/02/28 18:23
S10	405	S8 and S9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/26 21:07
S11	8594	((257/379) or (257/255) or (257/286) or (257/288) or (257/368) or (257/369) or (257/627) or (257/628) or (257/401)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/03/01 12:45
S12	6328	((438/197) or (438/198) or (438/199) or (438/200) or (438/210) or (438/238) or (438/239)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/03/01 12:46
S13	14351	S11 S12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/01 12:46
S14	9830	MISFET (Metal adj Insulated)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/01 12:47
S15	1280820	project\$4 same surface	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/01 12:48
S16	101646	gate adj (insulat\$4 dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/01 12:49

S17	118757	switch\$3 near5 capacitor	US-PGPUB;	OR	ON	2007/03/01 12:50
			USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB			
S18	0	S13 and S14 and S15 and S16 and S17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/01 12:51
S19	. 5	S13 and S14 and S16 and S17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/01 12:51
S20	34	S13 and S14 and S16 and S15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/01 12:51
S21	2	"20030034545"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/26 20:46
S22	·4	(("6734479") or ("5900657")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/26 20:45
S23	915	gate near3 width with (PMOS PFET)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/26 21:08
S24	10233	MISFET (Metal adj Insulated)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/09/26 21:08

S25	9	S24 and S23	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	ON	2007/09/26 21:08
			IBM_TDB			